

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

---

In re Patent Application of:  
Martin Peckerar et al.

Application No.: 10/768,747

Confirmation No.: 7954

Filed: January 23, 2004

Art Unit: 2822

For: Technique for perfecting the active regions of  
wide bandgap semiconductor nitride devices

Examiner: M. F. Guerrero

**RESPONSE TO FINAL ACTION UNDER 37 C.F.R. 1.116**

MS AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

In response to the Office Action dated June 6, 2006, finally rejecting claims 1-14, please see the following remarks:

**Remarks/Arguments** begin on page 2 of this paper.

Although it is not believed that additional fees are required along with this Response, any extension of time necessary to avoid abandonment of this application is hereby petitioned under 37 C.F.R. § 1.136(a) and any fees required are hereby authorized to be charged to Deposit Account No. 50-0281.